



A Product Line of Diodes Incorporated

ZXTN4000Z

#### 60V NPN LED DRIVING TRANSISTOR IN SOT89

#### Features

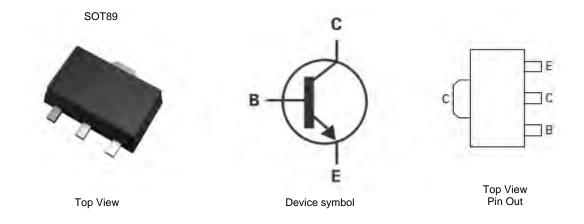
- BV<sub>CEO</sub> > 60V
- Max continuous current  $I_C = 1A$
- $h_{FE} > 100 @ I_C = 150mA, V_{CE} = 150mV$
- Lead Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

#### Applications

LED TV backlight



- Case: SOT89
- Case material: molded Plastic. "Green" molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.052 grams (Approximate)



## Ordering Information (Note 3)

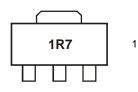
Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN4000ZTA	1S7	7	12	1000 units

1. No purposefully added lead.

2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

# **Marking Information**

Notes:



1R7 = Product Type Marking Code

<sup>3.</sup> For Packaging Details, go to our website at http://www.diodes.com.





#### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	lc	1	A
Peak Pulse Current (Note 4)	I <sub>CM</sub>	3	A
Base Current	IB	500	mA

#### Thermal Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

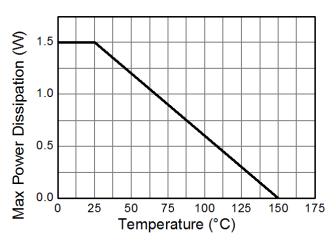
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	83	°C/W
Thermal Resistance, Junction to Leads (Note 6)	R <sub>θJL</sub>	28	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes: 4. Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ .

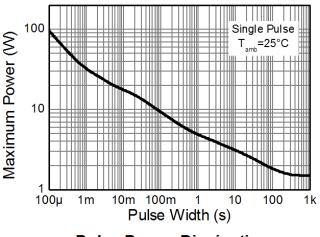
5. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions

6. Thermal resistance from junction to solder-point (at the end of the collector lead).

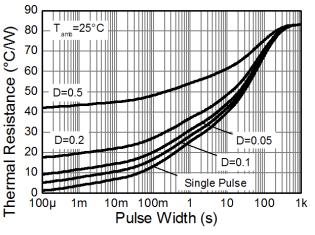
# Thermal Characteristics and Derating information



# **Derating Curve**



**Pulse Power Dissipation** 



# **Transient Thermal Impedance**





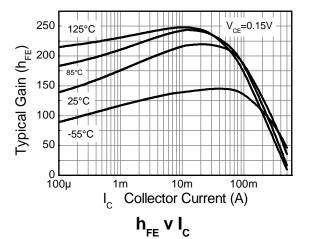
# ZXTN4000Z

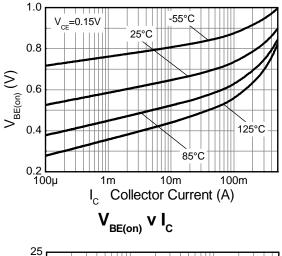
## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

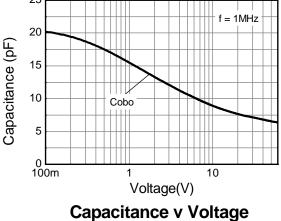
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	60		-	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	60		-	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.3	-	V	I <sub>E</sub> = 100μA
Collector Cut-off Current	I <sub>CBO</sub>	-	-	50	nA	$V_{CB} = 60V$
Emitter Cut-off Current	I <sub>EBO</sub>	-	-	50	nA	$V_{EB} = 7V$
Static Forward Current Transfer Ratio (Note 7)	h <sub>FE</sub>	60	-	-		I <sub>C</sub> = 85mA, V <sub>CE</sub> = 0.1V
Static Forward Current Transfer Ratio (Note 7)		100	-	-	-	$I_C = 150 \text{mA}, V_{CE} = 0.15 \text{V}$
Base-Emitter Turn-On Voltage (Note 7)	V <sub>BE(on)</sub>	-	0.76	0.95	V	$I_{C} = 150 \text{mA}, V_{CE} = 0.15 \text{V}$
Delay Time	t <sub>(d)</sub>	-	300	-	ns	
Rise Time	t(r)	-	292	-	ns	V <sub>CC</sub> = 48V, I <sub>C</sub> = 150mA,
Storage Time	t <sub>(s)</sub>	-	805	-	ns	-I <sub>B2</sub> = 1.5mA, V <sub>CE(ON)</sub> = 0.15V
Fall Time	t(f)	-	226	-	ns	
Storage Time	t <sub>(s)</sub>	-	25	-	ns	$V_{CC} = 48V, I_{C} = 150mA,$
Fall Time	t <sub>(f)</sub>	-	202	-	ns	-I <sub>B2</sub> = 1.5mA, V <sub>CE(ON)</sub> = 4V

Notes: 7. Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ 

**Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified





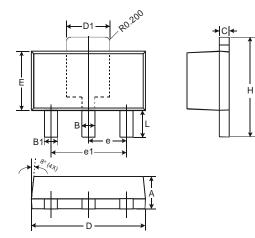


ZXTN4000Z Datasheet Number: DS35676 Rev. 1 - 2 Downloaded from <u>Elcodis.com</u> electronic components distributor



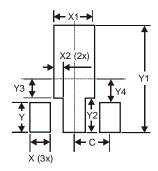


# Package Outline Dimensions



SOT89			
Dim	Min	Max	
Α	1.40	1.60	
В	0.44	0.62	
B1	0.35	0.54	
С	0.35	0.43	
D	4.40	4.60	
D1	1.52	1.83	
Е	2.29	2.60	
е	1.50 Typ		
e1	3.00 Typ		
Н	3.94	4.25	
L	0.89	1.20	
All D	All Dimensions in mm		

# Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500



#### **ZXTN4000Z**

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